

1. General description

The GTL2107 is a customized translator between dual Xeon processors, GTL–/GTL/GTL+ I/O and the Platform Health Management, South Bridge and Power Supply 3.3 V LVTTL and GTL signals.

2. Features

- Operates as a GTL to LVTTL sampling receiver or LVTTL to GTL driver
- Operates at GTL, GTL+ or GTL– levels
- EN1 and EN2 enable control
- 3.0 V to 3.6 V operation
- LVTTL I/O not 5 V tolerant
- Series termination on the LVTTL outputs of 30 Ω
- ESD protection exceeds 2000 V HBM per JESD22-A114, 150 V MM per JESD22-A115, and 1000 V CDM per JESD22-C101
- Latch-up testing is done to JEDEC Standard JESD78 Class II, Level A which exceeds 500 mA
- Package offered: TSSOP28

3. Quick reference data

Table 1. Quick reference data

$T_{amb} = 25\text{ }^{\circ}\text{C}$.

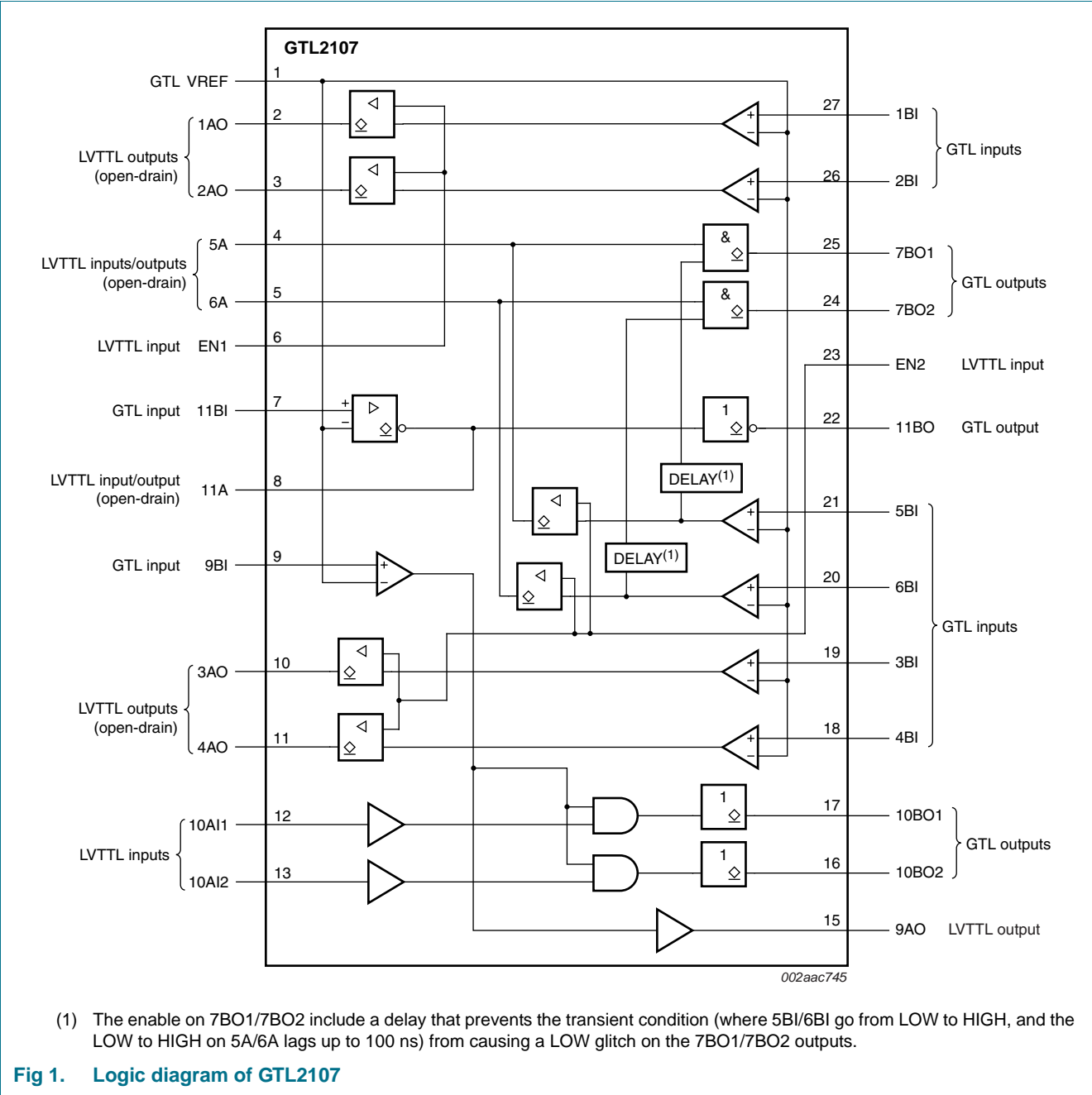
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V _{ref} = 0.73 V; V _{TT} = 1.1 V						
t _{PLH}	LOW to HIGH propagation delay	nA to nBI; see Figure 4	1	4	8	ns
		nBI to nA or nAO (open-drain outputs); see Figure 13	2	13	18	ns
t _{PHL}	HIGH to LOW propagation delay	nA to nBI; see Figure 4	2	5.5	10	ns
		nBI to nA or nAO (open-drain outputs); see Figure 13	2	4	10	ns
V _{ref} = 0.76 V; V _{TT} = 1.2 V						
t _{PLH}	LOW to HIGH propagation delay	nA to nBI; see Figure 4	1	4	8	ns
		nBI to nA or nAO (open-drain outputs); see Figure 13	2	13	18	ns
t _{PHL}	HIGH to LOW propagation delay	nA to nBI; see Figure 4	2	5.5	10	ns
		nBI to nA or nAO (open-drain outputs); see Figure 13	2	4	10	ns

4. Ordering information

Table 2. Ordering information
T_{amb} = -40 °C to +85 °C.

Type number	Topside mark	Package		Version
		Name	Description	
GTL2107PW	GTL2107	TSSOP28	plastic thin shrink small outline package; 28 leads; body width 4.4 mm	SOT361-1

5. Functional diagram



6. Pinning information

6.1 Pinning

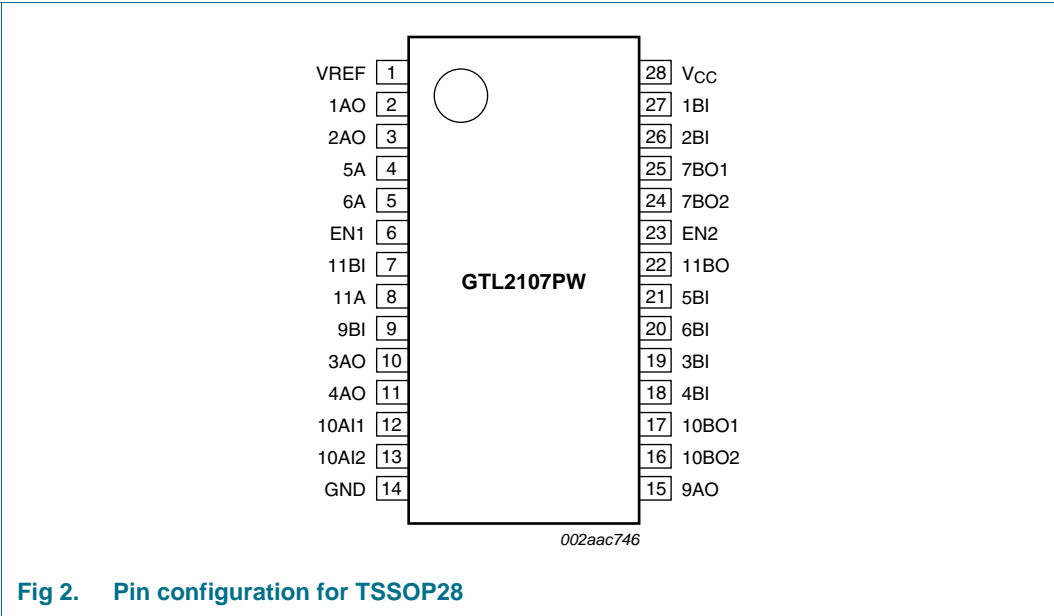


Fig 2. Pin configuration for TSSOP28

6.2 Pin description

Table 3. Pin description

Symbol	Pin	Description
VREF	1	GTL reference voltage
1AO	2	data output (LVTTL), open-drain
2AO	3	data output (LVTTL), open-drain
5A	4	data input/output (LVTTL), open-drain
6A	5	data input/output (LVTTL), open-drain
EN1	6	enable input (LVTTL)
11BI	7	data input (GTL)
11A	8	data input/output (LVTTL), open-drain
9BI	9	data input (GTL)
3AO	10	data output (LVTTL), open-drain
4AO	11	data output (LVTTL), open-drain
10AI1	12	data input (LVTTL)
10AI2	13	data input (LVTTL)
GND	14	ground (0 V)
9AO	15	data output (LVTTL), push-pull
10BO2	16	data output (GTL)
10BO1	17	data output (GTL)
4BI	18	data input (GTL)
3BI	19	data input (GTL)

Table 3. Pin description ...continued

Symbol	Pin	Description
6BI	20	data input (GTL)
5BI	21	data input (GTL)
11BO	22	data output (GTL)
EN2	23	enable input (LVTTTL)
7BO2	24	data output (GTL)
7BO1	25	data output (GTL)
2BI	26	data input (GTL)
1BI	27	data input (GTL)
V _{CC}	28	positive supply voltage

7. Functional description

Refer to [Figure 1 “Logic diagram of GTL2107”](#).

7.1 Function tables

Table 4. Power supervisor power good control

H = HIGH voltage level; L = LOW voltage level; X = Don't care.

Inputs		Output
EN1	1BI/2BI	1AO/2AO (open-drain)
H	L	L
H	H	H
L	X	H

Table 5. Power supervisor power good control

H = HIGH voltage level; L = LOW voltage level; X = Don't care.

Inputs		Output
EN2	3BI/4BI	3AO/4AO (open-drain)
H	L	L
H	H	H
L	X	H

Table 6. Southbridge SMI_L control

H = HIGH voltage level; L = LOW voltage level.

Input	Output
9BI	9AO (push-pull)
L	L
H	H

Table 7. CPU SMI_L control*H = HIGH voltage level; L = LOW voltage level.*

Inputs		Output
10AI1/10AI2	9BI	10BO1/10BO2
L	L	L
L	H	L
H	L	L
H	H	H

Table 8. PROCHOT L control*H = HIGH voltage level; L = LOW voltage level.*

Inputs		Input/output	Output
EN2	5BI/6BI	5A/6A (open-drain)	7BO1/7BO2
H	L	L	H ^[1]
H	H	L ^[2]	L
H	H	H	H
L	H	L ^[2]	L
L	H	H	H
L	L	H	H
L	L	L ^[2]	H

[1] The enable on 7BO1/7BO2 includes a delay that prevents the transient condition (where 5BI/6BI goes from LOW to HIGH, and the LOW to HIGH on 5A/6A lags up to 100 ns) from causing a low glitch on the 7BO1/7BO2 outputs.

[2] Open-drain input/output terminal is driven to logic LOW state by an external driver.

Table 9. Southbridge NMI control*H = HIGH voltage level; L = LOW voltage level.*

Input	Input/output	Output
11BI	11A (open-drain)	11BO
L	H	L
L	L ^[1]	H
H	L	H

[1] Open-drain input/output terminal is driven to logic LOW state by an external driver.

8. Application design-in information

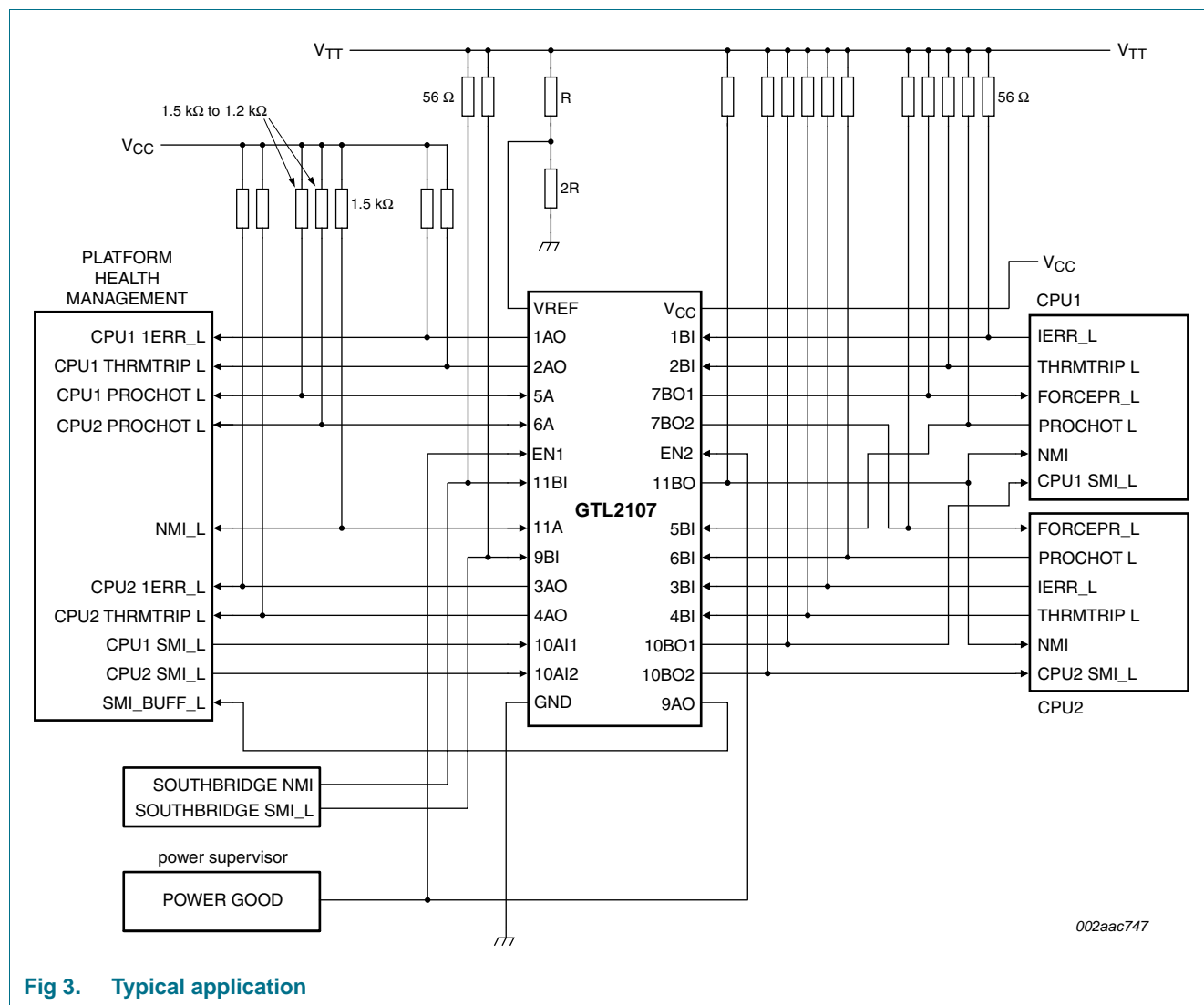


Fig 3. Typical application

9. Limiting values

Table 10. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		–0.5	+4.6	V
I_{IK}	input clamping current	$V_I < 0$ V	-	–50	mA
V_I	input voltage	A port (LVTTTL)	–0.5 ^[1]	+4.6	V
		B port (GTL)	–0.5 ^[1]	+4.6	V
I_{OK}	output clamping current	$V_O < 0$ V	-	–50	mA
V_O	output voltage	output in OFF or HIGH state; A port	–0.5 ^[1]	+4.6	V
		output in OFF or HIGH state; B port	–0.5 ^[1]	+4.6	V
I_{OL}	LOW-level output current ^[2]	A port	-	32	mA
		B port	-	30	mA
I_{OH}	HIGH-level output current ^[3]	A port	-	–32	mA
T_{stg}	storage temperature		–60	+150	°C
$T_{j(max)}$	maximum junction temperature		^[4] -	+125	°C

[1] The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

[2] Current into any output in the LOW state.

[3] Current into any output in the HIGH state.

[4] The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150 °C.

10. Recommended operating conditions

Table 11. Operating conditions

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{CC}	supply voltage		3.0	3.3	3.6	V
V_{TT}	termination voltage	GTL–	0.85	0.9	0.95	V
		GTL	1.14	1.2	1.26	V
		GTL+	1.35	1.5	1.65	V
V_{ref}	reference voltage	overall	0.5	$\frac{2}{3}V_{TT}$	1.8	V
		GTL–	0.5	0.6	0.63	V
		GTL	0.76	0.8	0.84	V
		GTL+	0.87	1	1.1	V
V_I	input voltage	A port	0	3.3	3.6	V
		B port	0	V_{TT}	3.6	V
V_{IH}	HIGH-level input voltage	A port and ENn	2	-	-	V
		B port	$V_{ref} + 0.050$	-	-	V
V_{IL}	LOW-level input voltage	A port and ENn	-	-	0.8	V
		B port	-	-	$V_{ref} - 0.050$	V
I_{OH}	HIGH-level output current	A port	-	-	–16	mA

Table 11. Operating conditions ...continued

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
I _{OL}	LOW-level output current	A port	-	-	16	mA
		B port	-	-	15	mA
T _{amb}	ambient temperature	operating in free-air	-40	-	+85	°C

11. Static characteristics

Table 12. Static characteristics

Recommended operating conditions; voltages are referenced to GND (ground = 0 V). T_{amb} = -40 °C to +85 °C.

Symbol	Parameter	Conditions	Min	Typ ^[1]	Max	Unit
V _{OH}	HIGH-level output voltage	9AO; V _{CC} = 3.0 V to 3.6 V; I _{OH} = -100 µA	[2] V _{CC} - 0.2	3.0	-	V
		9AO; V _{CC} = 3.0 V; I _{OH} = -16 mA	[2] 2.1	2.3	-	V
V _{OL}	LOW-level output voltage	A port; V _{CC} = 3.0 V; I _{OL} = 4 mA	[2] -	0.15	0.4	V
		A port; V _{CC} = 3.0 V; I _{OL} = 8 mA	[2] -	0.3	0.55	V
		A port; V _{CC} = 3.0 V; I _{OL} = 16 mA	[2] -	0.6	0.8	V
		B port; V _{CC} = 3.0 V; I _{OL} = 15 mA	[2] -	0.13	0.4	V
I _{OH}	HIGH-level output current	open-drain outputs; A port other than 9AO; V _O = V _{CC} ; V _{CC} = 3.6 V	-	-	±1	µA
I _I	input current	A port; V _{CC} = 3.6 V; V _I = V _{CC}	-	-	±1	µA
		A port; V _{CC} = 3.6 V; V _I = 0 V	-	-	±1	µA
		B port; V _{CC} = 3.6 V; V _I = V _{TT} or GND	-	-	±1	µA
I _{CC}	supply current	A or B port; V _{CC} = 3.6 V; V _I = V _{CC} or GND; I _O = 0 mA	-	8	12	mA
ΔI _{CC} ^[3]	additional supply current	per input; A port or control inputs; V _{CC} = 3.6 V; V _I = V _{CC} - 0.6 V	-	-	500	µA
C _{io}	input/output capacitance	A port; V _O = 3.0 V or 0 V	-	5.0	-	pF
		B port; V _O = V _{TT} or 0 V	-	4.0	-	pF

[1] All typical values are measured at V_{CC} = 3.3 V and T_{amb} = 25 °C.

[2] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[3] This is the increase in supply current for each input that is at the specified LVTTTL voltage level rather than V_{CC} or GND.

12. Dynamic characteristics

Table 13. Dynamic characteristics

$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$.

Symbol	Parameter	Conditions	Min	Typ ^[1]	Max	Unit
$V_{ref} = 0.73 \text{ V}$; $V_{TT} = 1.1 \text{ V}$						
t_{PLH}	LOW to HIGH propagation delay	nA to nBI; see Figure 4	1	4	8	ns
		9BI to 9AO; see Figure 5	2	5.5	10	ns
		nBI to nA or nAO (open-drain outputs); see Figure 13	2	13	18	ns
		9BI to 10BOn	2	6	11	ns
		11A to 11BO; see Figure 10	1	4	8	ns
		11BI to 11A; see Figure 9	2	7.5	11	ns
		11BI to 11BO	2	8	13	ns
		5BI to 7BO1 or 6BI to 7BO2; see Figure 7	4	7	11	ns
t_{PHL}	HIGH to LOW propagation delay	nA to nBI; see Figure 4	2	5.5	10	ns
		9BI to 9AO; see Figure 5	2	5.5	10	ns
		nBI to nA or nAO (open-drain outputs); see Figure 13	2	4	10	ns
		9BI to 10BOn	2	6	11	ns
		11A to 11BO; see Figure 10	1	5.5	10	ns
		11BI to 11A; see Figure 9	2	8.5	13	ns
		11BI to 11BO	^[2] 2	14	21	ns
		5BI to 7BO1 or 6BI to 7BO2; see Figure 7	100	205	350	ns
t_{PLZ}	LOW to OFF-state propagation delay	EN1 to nAO or EN2 to nAO; see Figure 8	1	3	7	ns
		EN1 to 5A (I/O) or EN2 to 6A (I/O); see Figure 8	1	3	7	ns
t_{PZL}	OFF-state to LOW propagation delay	EN1 to nAO or EN2 to nAO; see Figure 8	1	3	7	ns
		EN1 to 5A (I/O) or EN2 to 6A (I/O); see Figure 8	1	3	7	ns

Table 13. Dynamic characteristics ...continued

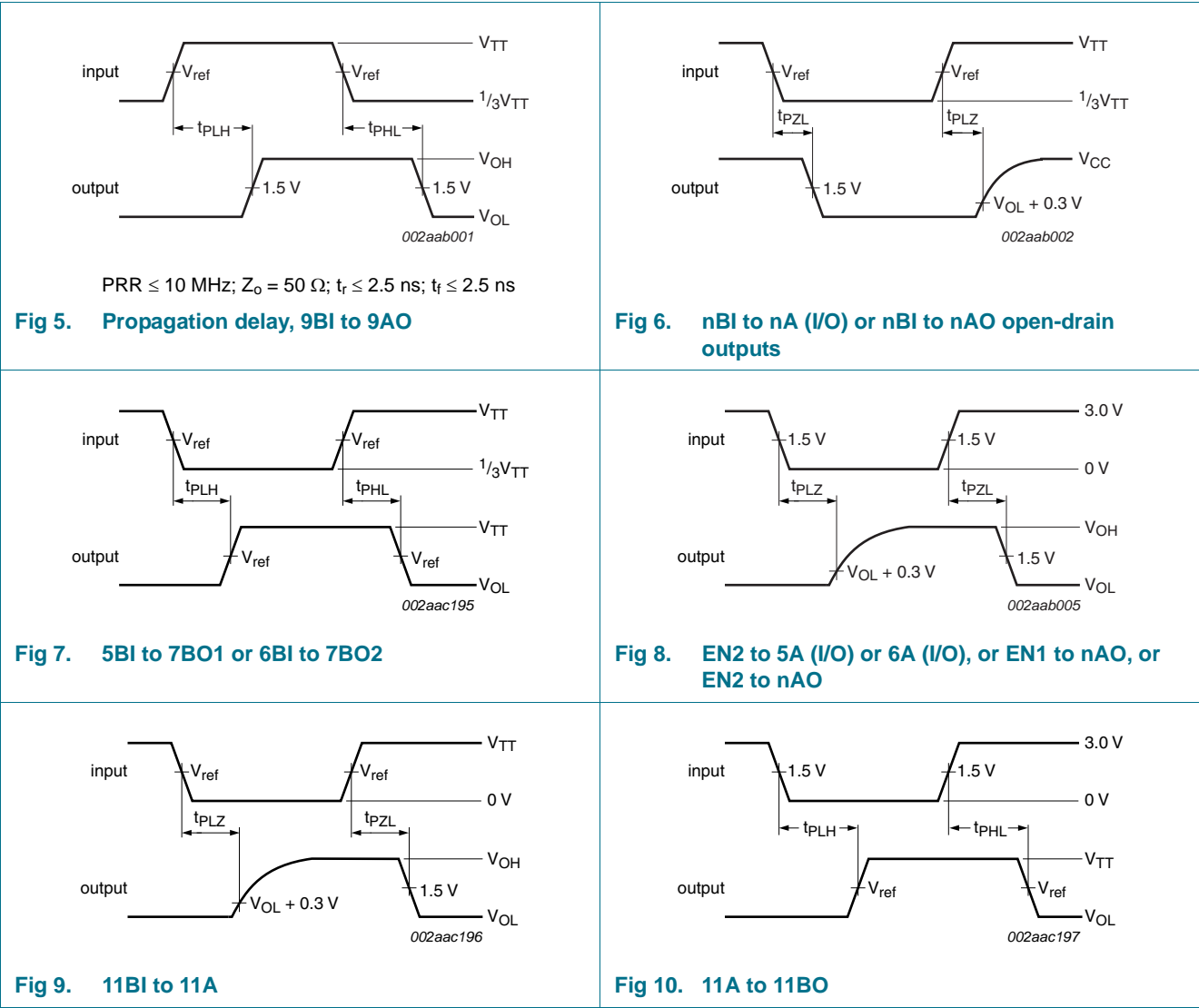
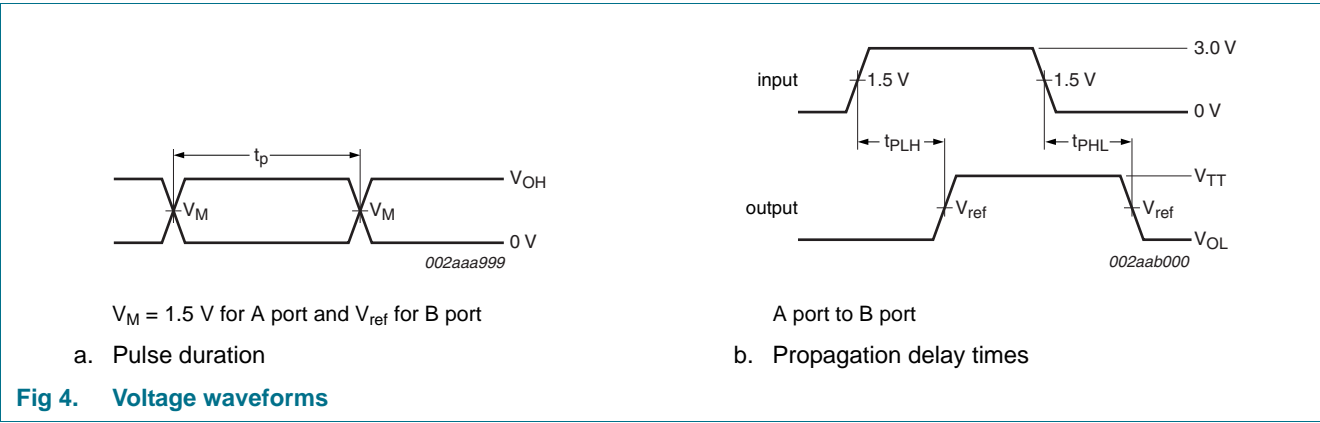
 $V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$.

Symbol	Parameter	Conditions	Min	Typ ^[1]	Max	Unit
$V_{ref} = 0.76\text{ V}$; $V_{TT} = 1.2\text{ V}$						
t_{PLH}	LOW to HIGH propagation delay	nA to nBI; see Figure 4	1	4	8	ns
		9BI to 9AO; see Figure 5	2	5.5	10	ns
		nBI to nA or nAO (open-drain outputs); see Figure 13	2	13	18	ns
		9BI to 10BOn	2	6	11	ns
		11A to 11BO; see Figure 10	1	4	8	ns
		11BI to 11A; see Figure 9	2	7.5	11	ns
		11BI to 11BO	2	8	13	ns
		5BI to 7BO1 or 6BI to 7BO2; see Figure 7	4	7	11	ns
t_{PHL}	HIGH to LOW propagation delay	nA to nBI; see Figure 4	2	5.5	10	ns
		9BI to 9AO; see Figure 5	2	5.5	10	ns
		nBI to nA or nAO (open-drain outputs); see Figure 13	2	4	10	ns
		9BI to 10BOn	2	6	11	ns
		11A to 11BO; see Figure 10	1	5.5	10	ns
		11BI to 11A; see Figure 9	2	8.5	13	ns
		11BI to 11BO	^[2] 2	14	21	ns
		5BI to 7BO1 or 6BI to 7BO2; see Figure 7	100	205	350	ns
t_{PLZ}	LOW to OFF-state propagation delay	EN1 to nAO or EN2 to nAO; see Figure 8	1	3	7	ns
		EN1 to 5A (I/O) or EN2 to 6A (I/O); see Figure 8	1	3	7	ns
t_{PZL}	OFF-state to LOW propagation delay	EN1 to nAO or EN2 to nAO; see Figure 8	1	3	7	ns
		EN1 to 5A (I/O) or EN2 to 6A (I/O); see Figure 8	1	3	7	ns

[1] All typical values are at $V_{CC} = 3.3\text{ V}$ and $T_{amb} = 25\text{ }^{\circ}\text{C}$.[2] Includes ~7.6 ns RC rise time of test load pull-up on 11A, 1.5 k Ω pull-up and 21 pF load on 11A has about 23 ns RC rise time.

12.1 Waveforms

$V_M = 1.5\text{ V}$ at $V_{CC} \geq 3.0\text{ V}$ for A ports; $V_M = V_{ref}$ for B ports.



13. Test information

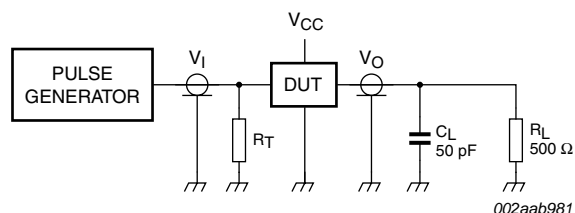


Fig 11. Load circuit for A outputs (9AO)

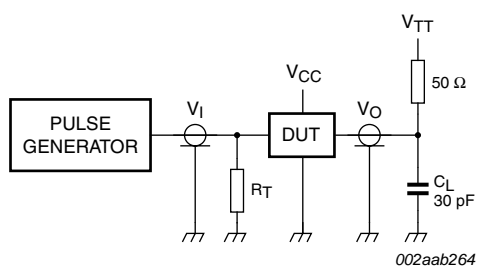


Fig 12. Load circuit for B outputs

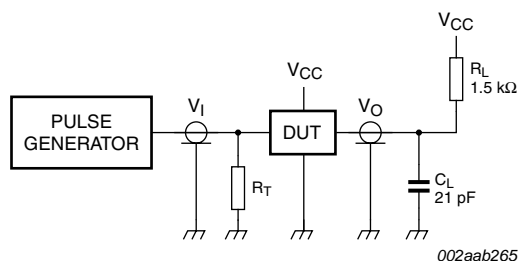


Fig 13. Load circuit for open-drain LVTTTL I/O and open-drain outputs

R_L — Load resistor

C_L — Load capacitance; includes jig and probe capacitance

R_T — Termination resistance; should be equal to Z_o of pulse generators.

14. Package outline

TSSOP28: plastic thin shrink small outline package; 28 leads; body width 4.4 mm

SOT361-1

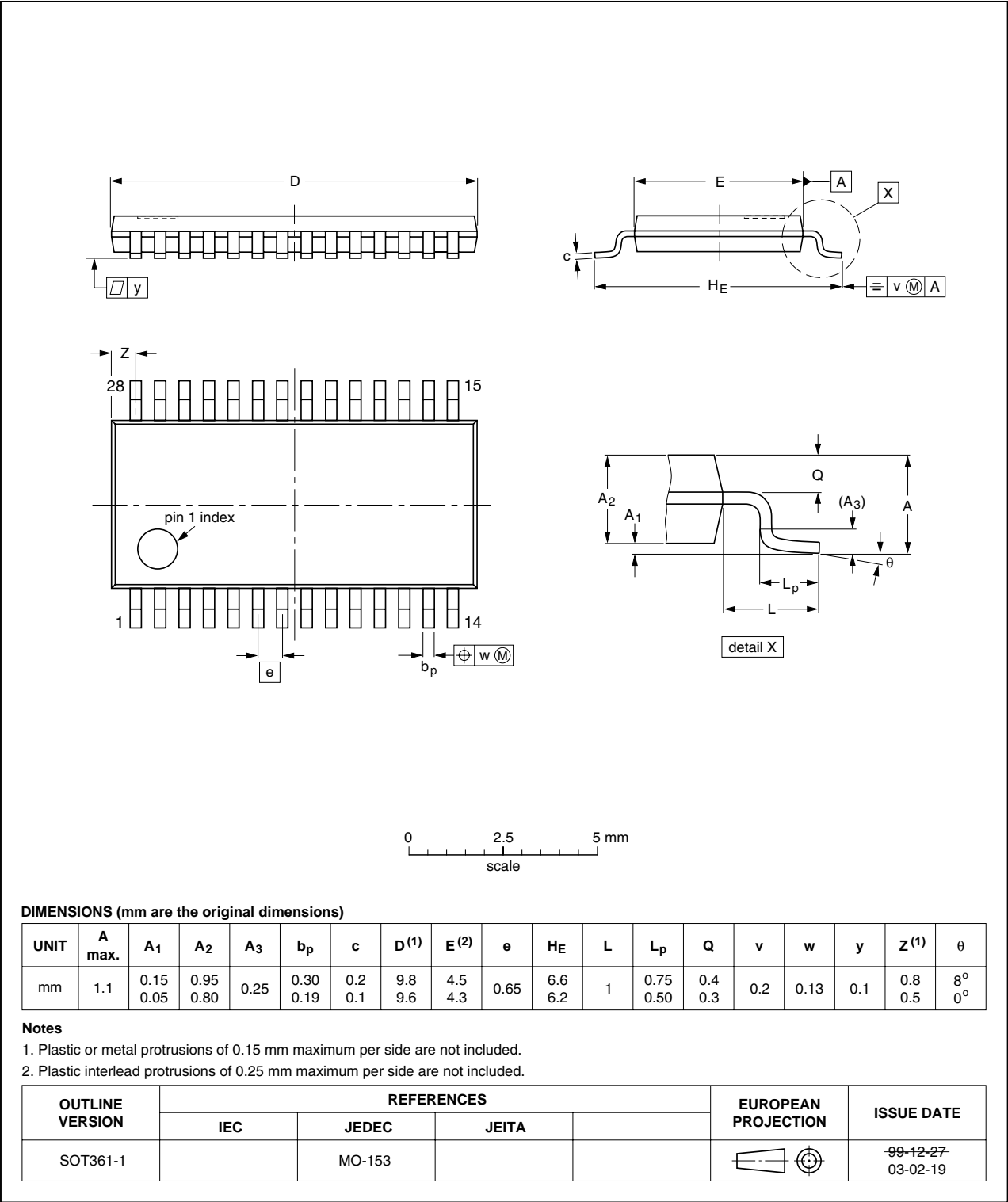


Fig 14. Package outline SOT361-1 (TSSOP28)

15. Soldering of SMD packages

This text provides a very brief insight into a complex technology. A more in-depth account of soldering ICs can be found in Application Note *AN10365 "Surface mount reflow soldering description"*.

15.1 Introduction to soldering

Soldering is one of the most common methods through which packages are attached to Printed Circuit Boards (PCBs), to form electrical circuits. The soldered joint provides both the mechanical and the electrical connection. There is no single soldering method that is ideal for all IC packages. Wave soldering is often preferred when through-hole and Surface Mount Devices (SMDs) are mixed on one printed wiring board; however, it is not suitable for fine pitch SMDs. Reflow soldering is ideal for the small pitches and high densities that come with increased miniaturization.

15.2 Wave and reflow soldering

Wave soldering is a joining technology in which the joints are made by solder coming from a standing wave of liquid solder. The wave soldering process is suitable for the following:

- Through-hole components
- Leaded or leadless SMDs, which are glued to the surface of the printed circuit board

Not all SMDs can be wave soldered. Packages with solder balls, and some leadless packages which have solder lands underneath the body, cannot be wave soldered. Also, leaded SMDs with leads having a pitch smaller than ~0.6 mm cannot be wave soldered, due to an increased probability of bridging.

The reflow soldering process involves applying solder paste to a board, followed by component placement and exposure to a temperature profile. Leaded packages, packages with solder balls, and leadless packages are all reflow solderable.

Key characteristics in both wave and reflow soldering are:

- Board specifications, including the board finish, solder masks and vias
- Package footprints, including solder thieves and orientation
- The moisture sensitivity level of the packages
- Package placement
- Inspection and repair
- Lead-free soldering versus SnPb soldering

15.3 Wave soldering

Key characteristics in wave soldering are:

- Process issues, such as application of adhesive and flux, clinching of leads, board transport, the solder wave parameters, and the time during which components are exposed to the wave
- Solder bath specifications, including temperature and impurities

15.4 Reflow soldering

Key characteristics in reflow soldering are:

- Lead-free versus SnPb soldering; note that a lead-free reflow process usually leads to higher minimum peak temperatures (see [Figure 15](#)) than a SnPb process, thus reducing the process window
- Solder paste printing issues including smearing, release, and adjusting the process window for a mix of large and small components on one board
- Reflow temperature profile; this profile includes preheat, reflow (in which the board is heated to the peak temperature) and cooling down. It is imperative that the peak temperature is high enough for the solder to make reliable solder joints (a solder paste characteristic). In addition, the peak temperature must be low enough that the packages and/or boards are not damaged. The peak temperature of the package depends on package thickness and volume and is classified in accordance with [Table 14](#) and [15](#)

Table 14. SnPb eutectic process (from J-STD-020C)

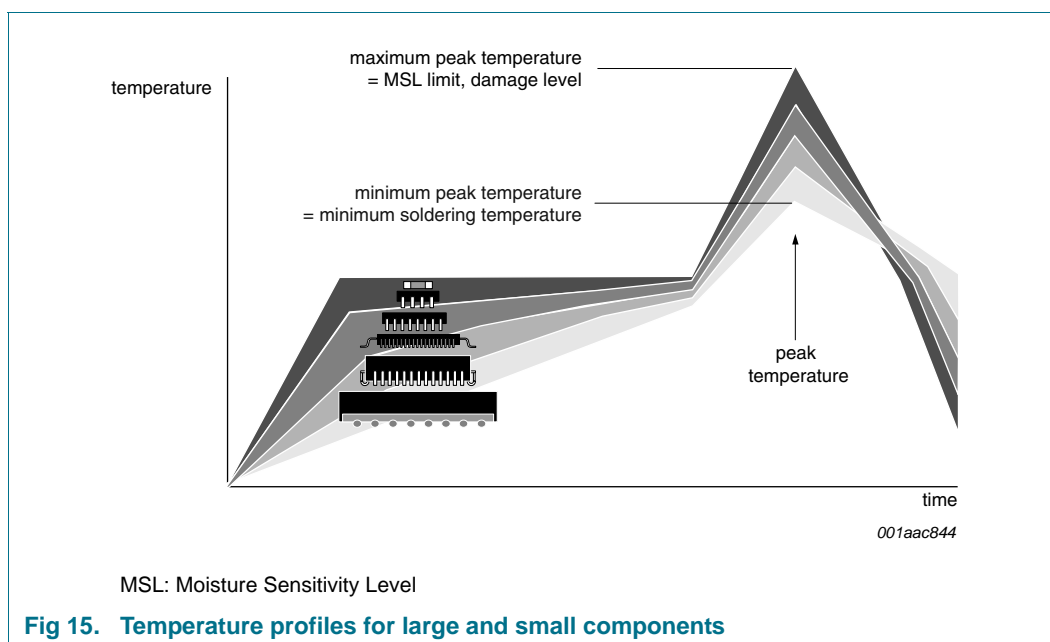
Package thickness (mm)	Package reflow temperature (°C)	
	Volume (mm ³)	
	< 350	≥ 350
< 2.5	235	220
≥ 2.5	220	220

Table 15. Lead-free process (from J-STD-020C)

Package thickness (mm)	Package reflow temperature (°C)		
	Volume (mm ³)		
	< 350	350 to 2000	> 2000
< 1.6	260	260	260
1.6 to 2.5	260	250	245
> 2.5	250	245	245

Moisture sensitivity precautions, as indicated on the packing, must be respected at all times.

Studies have shown that small packages reach higher temperatures during reflow soldering, see [Figure 15](#).



For further information on temperature profiles, refer to Application Note *AN10365* “Surface mount reflow soldering description”.

16. Abbreviations

Table 16. Abbreviations

Acronym	Description
CDM	Charged Device Model
CPU	Central Processing Unit
DUT	Device Under Test
ESD	ElectroStatic Discharge
GTL	Gunning Transceiver Logic
HBM	Human Body Model
LVTTTL	Low Voltage Transistor-Transistor Logic
MM	Machine Model
PRR	Pulse Rate Repetition

17. Revision history

Table 17. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
GTL2107_5	20091223	Product data sheet		GTL2107_4
Modifications: <ul style="list-style-type: none"> • Section 2 “Features”, 7th bullet item: changed from “200 V MM per JESD22-A115” to “150 V MM per JESD22-A115” • Table 1 “Quick reference data”: removed symbol/parameter “C_{io}, input/output capacitance” • Table 12 “Static characteristics”: <ul style="list-style-type: none"> – C_{io} (A port) Typ value changed from “3.0 pF” to “5.0 pF” – C_{io} (A port) Max value changed from “4.0 pF” to “-” – C_{io} (B port) Typ value changed from “2.0 pF” to “4.0 pF” – C_{io} (B port) Max value changed from “3.0 pF” to “-” • Table 13 “Dynamic characteristics”: <ul style="list-style-type: none"> – (sub-section V_{ref} = 0.73 V; V_{TT} = 1.1 V) deleted t_{PHZ} specification – (sub-section V_{ref} = 0.73 V; V_{TT} = 1.1 V) deleted t_{PZH} specification – (sub-section V_{ref} = 0.76 V; V_{TT} = 1.2 V) deleted t_{PHZ} specification – (sub-section V_{ref} = 0.76 V; V_{TT} = 1.2 V) deleted t_{PZH} specification • Figure 8 title changed from “EN1 to 5A (I/O) or EN2 to 6A (I/O) or EN1 to nAO or EN2 to nAO” to “EN2 to 5A (I/O) or 6A (I/O), or EN1 to nAO, or EN2 to nAO” • Deleted (old) Figure 11 “EN2 to 9AO” • Deleted (old) Figure 15 “Load circuit for 9AO OFF-state to LOW and LOW to OFF-state” 				
GTL2107_4	20070706	Product data sheet	-	GTL2107_3
GTL2107_3	20070129	Objective data sheet	-	GTL2008_GTL2107_2
GTL2008_GTL2107_2	20060926	Product data sheet	-	GTL2008_1
GTL2008_1	20060502	Product data sheet	-	-

18. Legal information

18.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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Date of release: 23 December 2009

Document identifier: GTL2107_5

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